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# **Self-homodyne RF-optical microdisk receiver**

**Mani Hossein-Zadeh and A.F.J Levi**

**Advanced Network Technology Lab.**

**University of Southern California**

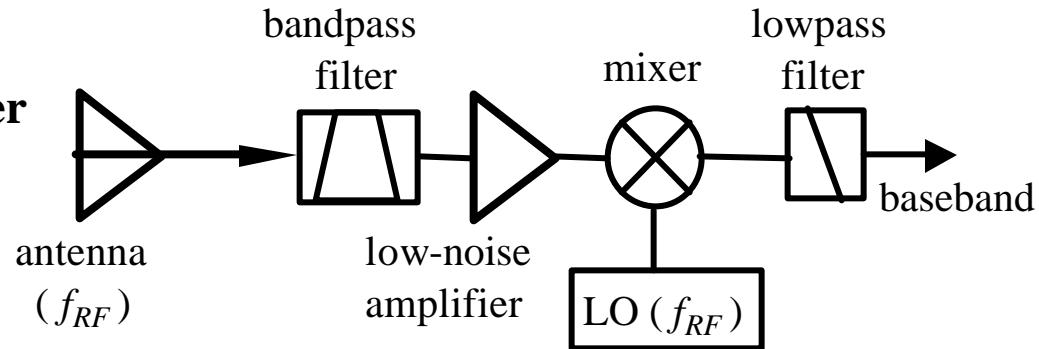
**CLEO 2004**

**San Fransisco, May 19<sup>th</sup> 2004**

# Conventional and microphotonic RF receiver architecture

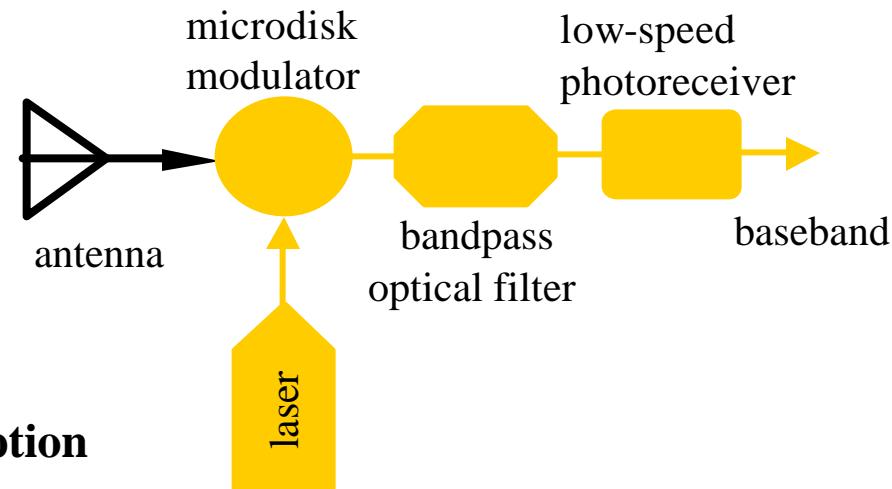
## ■ Conventional electronic direct-conversion (homodyne) receiver architecture

- ◆ High-speed electronics
  - ◊ local oscillator at carrier frequency ( $f_{RF}$ )
  - ◊ low-noise amplifier
  - ◊ RF mixer
- ◆ RF filters



## ■ Microphotonic RF receiver architecture

- ◆ Photonic components
  - ◊ microdisk optical modulator
  - ◊ optical filter
  - ◊ DFB laser
  - ◊ low-speed photoreceiver
- ◆ No high-speed electronics
- ◆ No conventional local oscillator
- ◆ No RF mixer
- ◆ Reduced size and power consumption
- ◆ Insensitive to RF carrier frequency
- ◆ Optical isolation



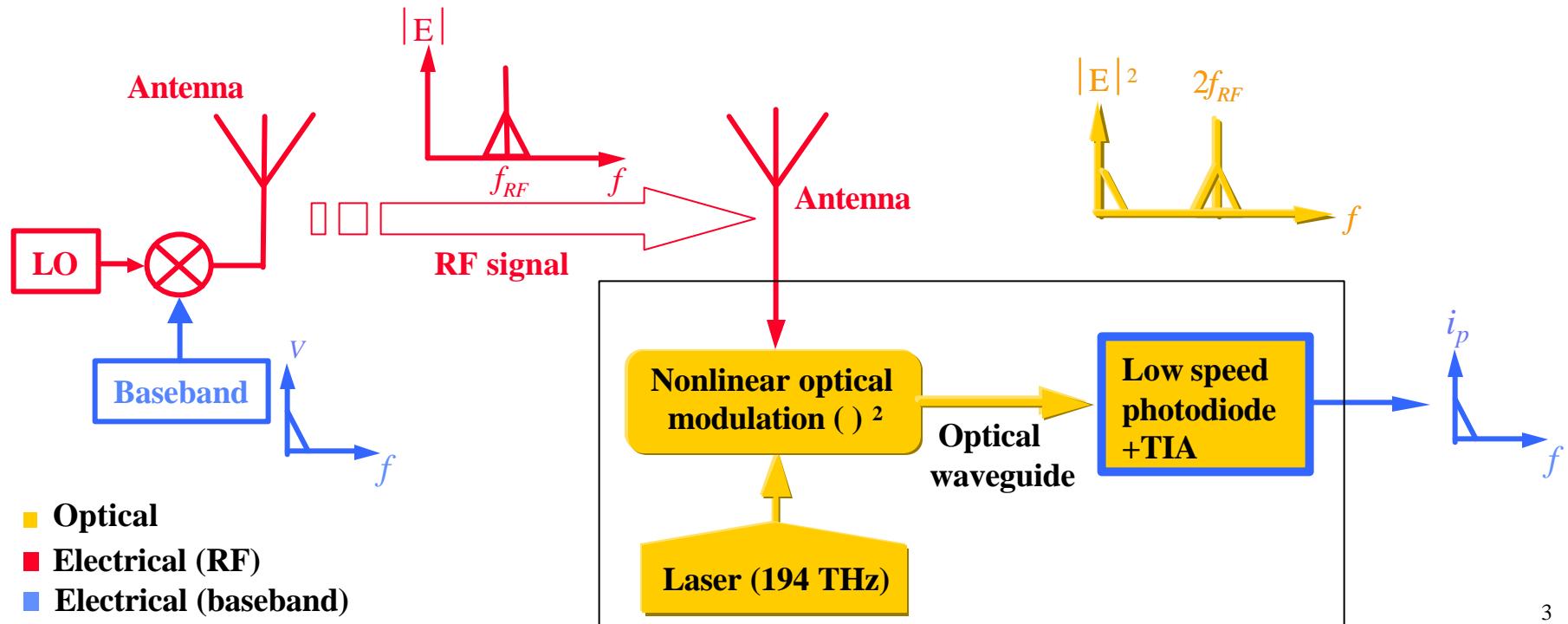
# Self-homodyne RF-photonics receiver

## ■ Transmitted carrier RF format

- ◆ Nonlinear mixing of carrier and sidebands in the receiver
- ◆ No local oscillator required

## ■ Photonic baseband down-conversion

- ◆ Second-order nonlinear modulation with optical transfer function ( $P_o \propto V_{RF}^2$ )



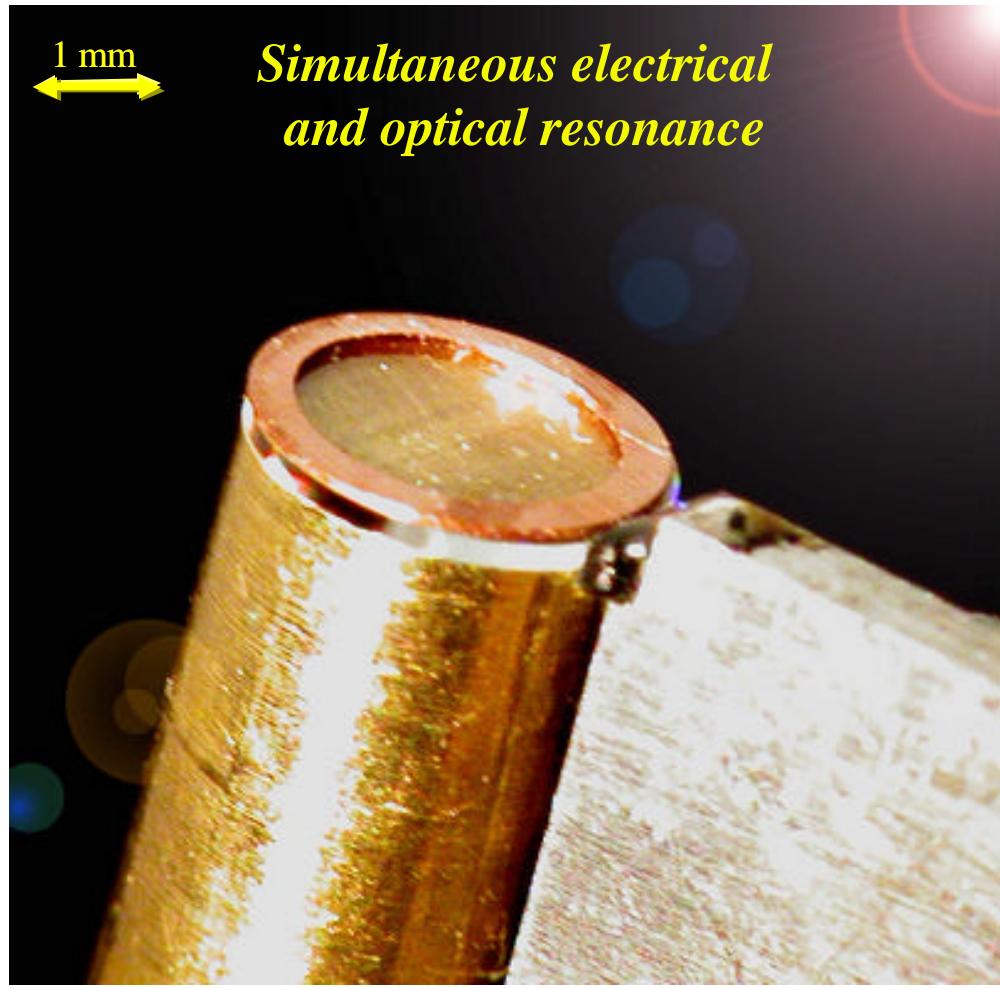
# RF-photonic LiNbO<sub>3</sub> microdisk technology

## ■ LiNbO<sub>3</sub> microdisk modulator

- ◆ Small volume:  $3 \text{ mm}^3 = p \times 3 \times 0.4 \text{ mm}^3$
- ◆ large electro-optical coefficient  
( $r_{33} = 30.8 \times 10^{-12} \text{ m/V}$ )
- ◆ High-Q optical whispering-gallery (WG) resonance:  
 $2 \times 10^6 - 6 \times 10^6$  (loaded),  $1.2 \times 10^7$  (unloaded)
- ◆ Long photon life time :  
1.6 – 5 ns (loaded), 9.5 ns (unloaded)
- ◆ Long interaction length:  
0.2-0.7 m (loaded), 1.3 m (unloaded)
- ◆ High-Q RF resonator :  
 $70 - 90$  (loaded),  $G_v \propto v Q_{\text{RF}}$

## ■ RF-photonic application

- ◆ Optical modulation
  - ❖ low power optical amplitude modulation
- ◆ RF signal processing in optical domain
  - ❖ high-frequency operation
    - low loss in optical domain
  - ❖ reduced power consumption
    - laser diode local oscillator
  - ❖ optical isolation



*Simultaneous electrical and optical resonance*

Combination of *microdisk* and *RF-photonic* technology demonstrated in RF-photonic LiNbO<sub>3</sub> microdisk receiver

# $\text{LiNbO}_3$ microdisk modulator

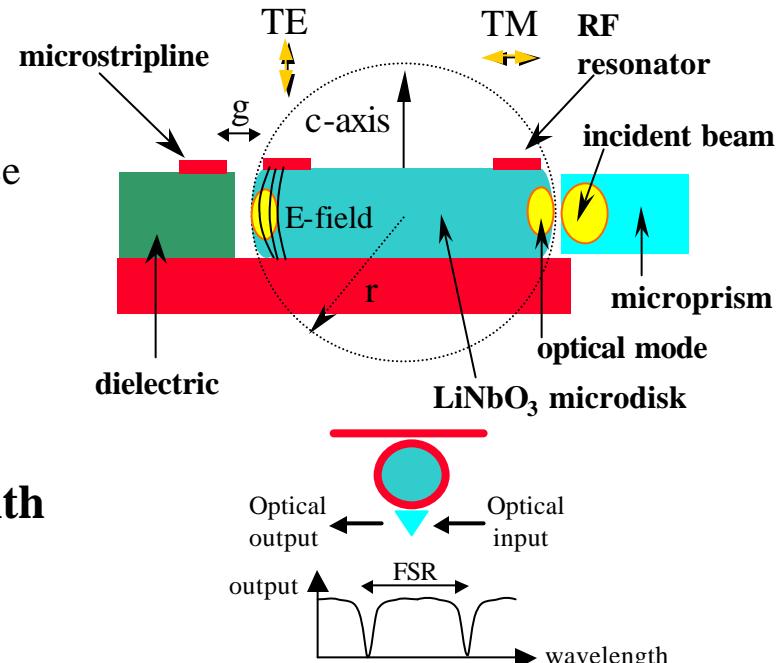
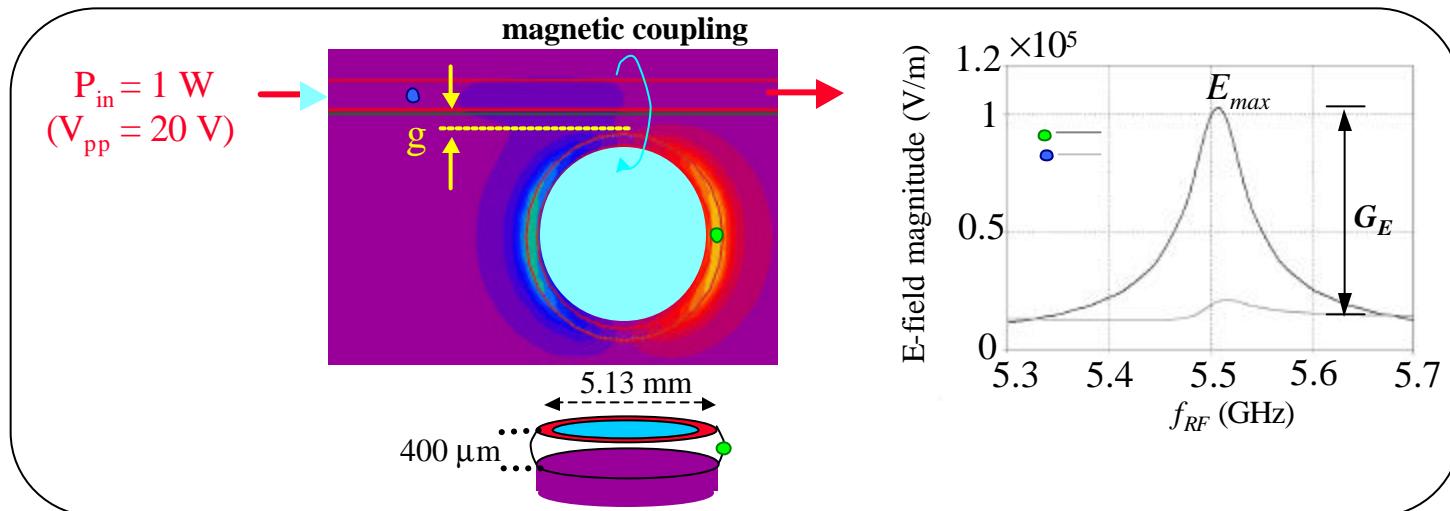
## ■ $\text{LiNbO}_3$ microdisk modulator

- ♦ Increased RF sensitivity and low power

- ♦ RF and optical signal in *simultaneous* resonance
- ♦ RF resonance provides voltage gain
- ♦ high- $Q$  ( $> 10^6$ ) whispering gallery(WG) mode provide long RF-photon interaction time
- ♦ photons highly confined at edge allowing high RF-photon spatial overlap

- ♦ Modulation only occurs at  $f_{RF} = m \cdot n_{FSR}$  with a bandwidth of  $Dn = n_0/Q$   
( $n_{FSR}$ = optical free spectral range,  $m$  : integer)

### Simulated RF resonance



# Linear and nonlinear modulation

## Received signal

$$V_{RF} = (1 + m \cos(\omega_b)) \cos(\omega_{RF})$$

**Microdisk optical mixer** ( $l_{\text{laser}} = l_{\text{res}}$ )

$$P_o(V_{RF}) = N_0 + \frac{1}{2} N_2 V_{RF}^2 + \dots$$

$$N_2 = \left. \frac{d^2 P_o}{d V_{RF}^2} \right|_{V_{RF}=0} = f(G_V, Q, P_{o,in}, k, b_E, t)$$

$G_V$  : voltage gain

$Q$  : optical Q-factor

$P_{o,in}$  : input optical power

$b_E$  : E-field correction factor

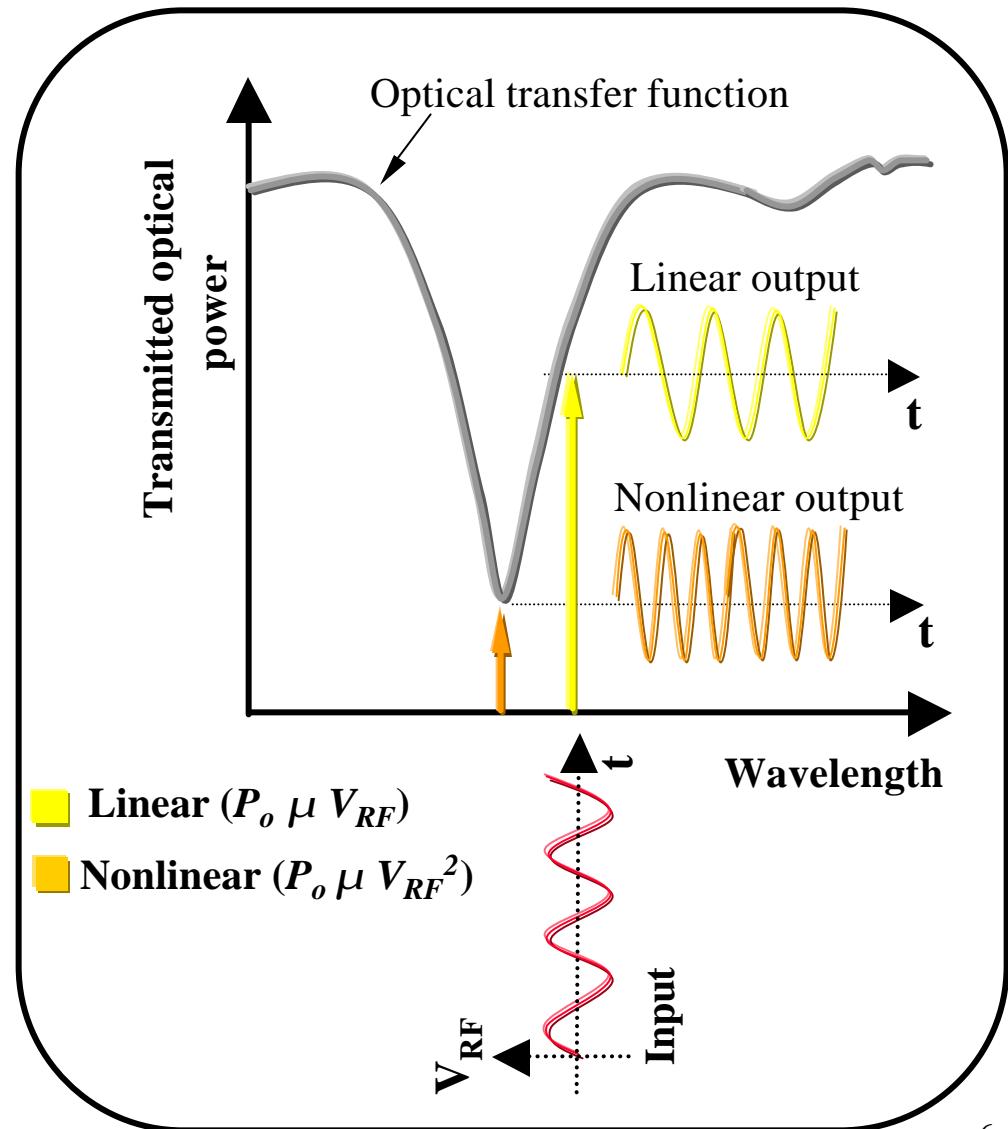
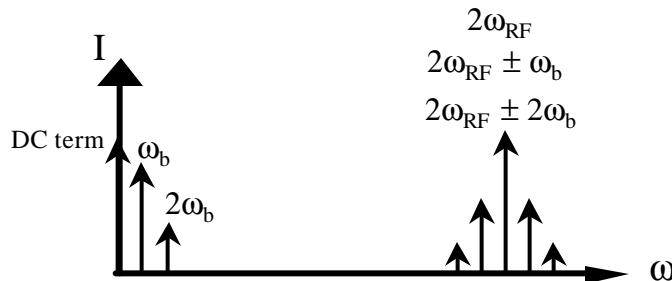
$t$  : disk thickness

$k$  : optical coupling factor

$R$  : photodetector responsivity

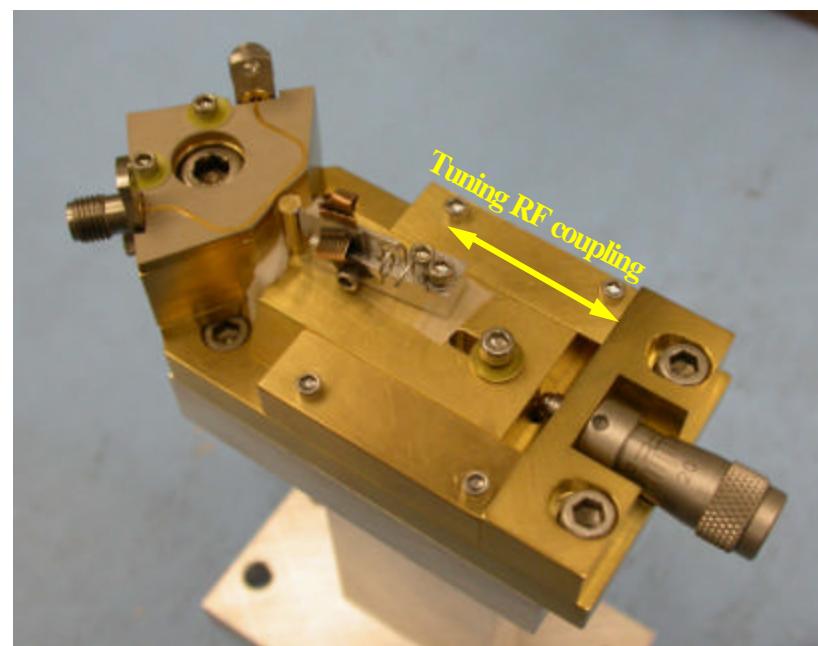
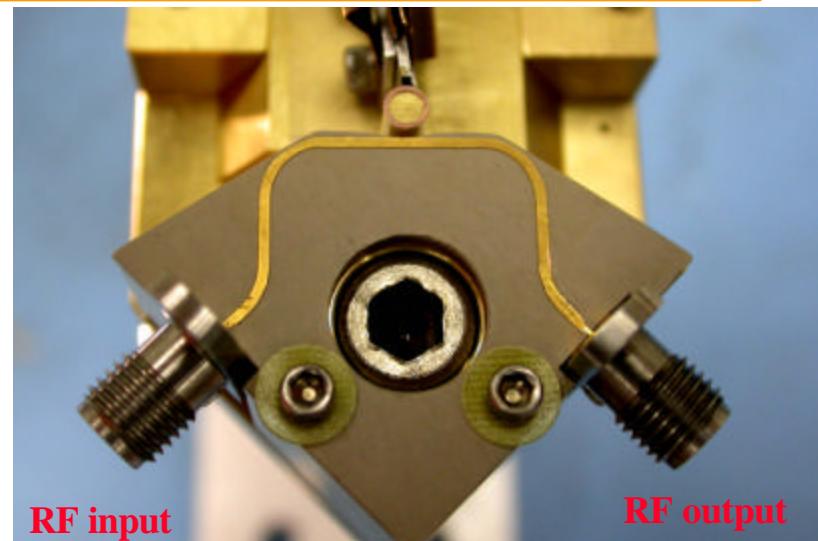
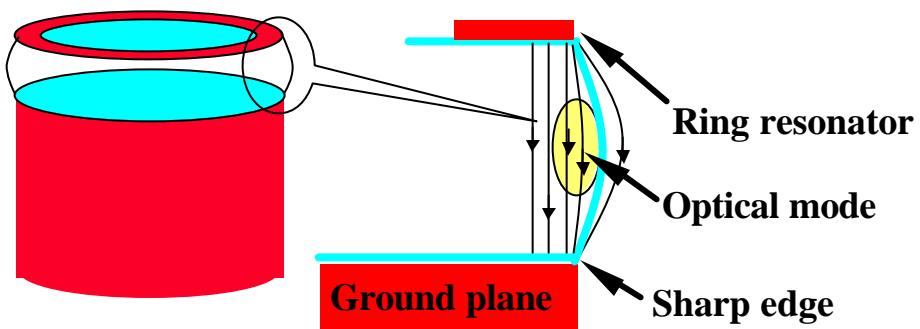
$$I(V_{RF}) = R P_o(V_{RF}) = R(N_0 + \frac{1}{2} N_2 V_{RF}^2 + \dots)$$

$$I_{w_b} \approx R \frac{m}{2} N_2 V_{RF}^2$$



# 14.6 GHz LiNbO<sub>3</sub> microdisk modulator

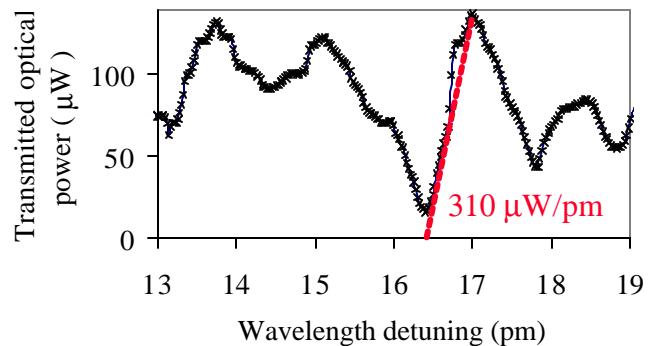
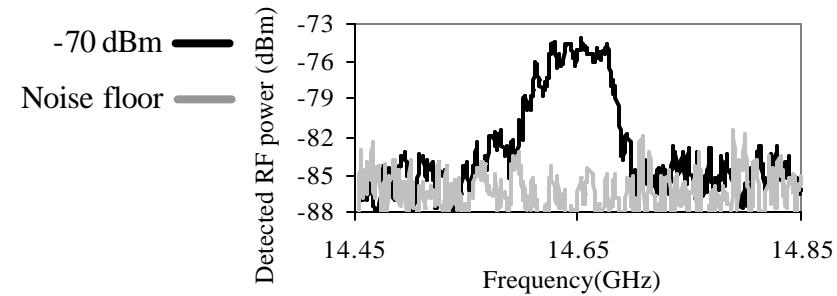
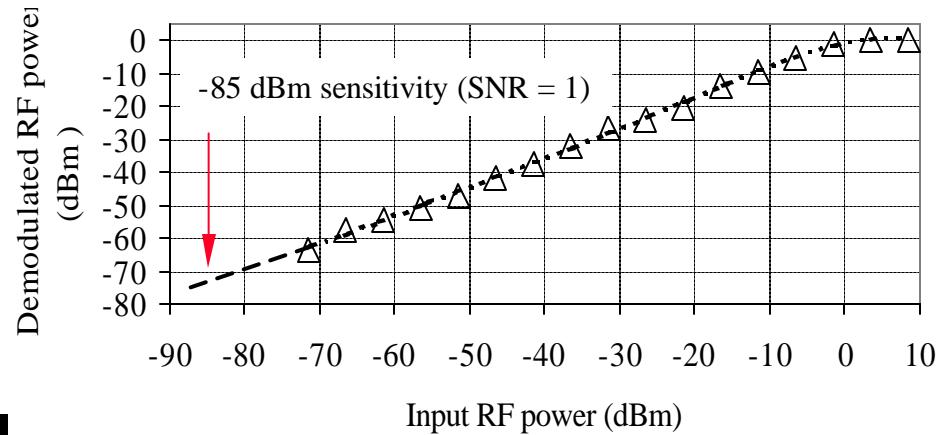
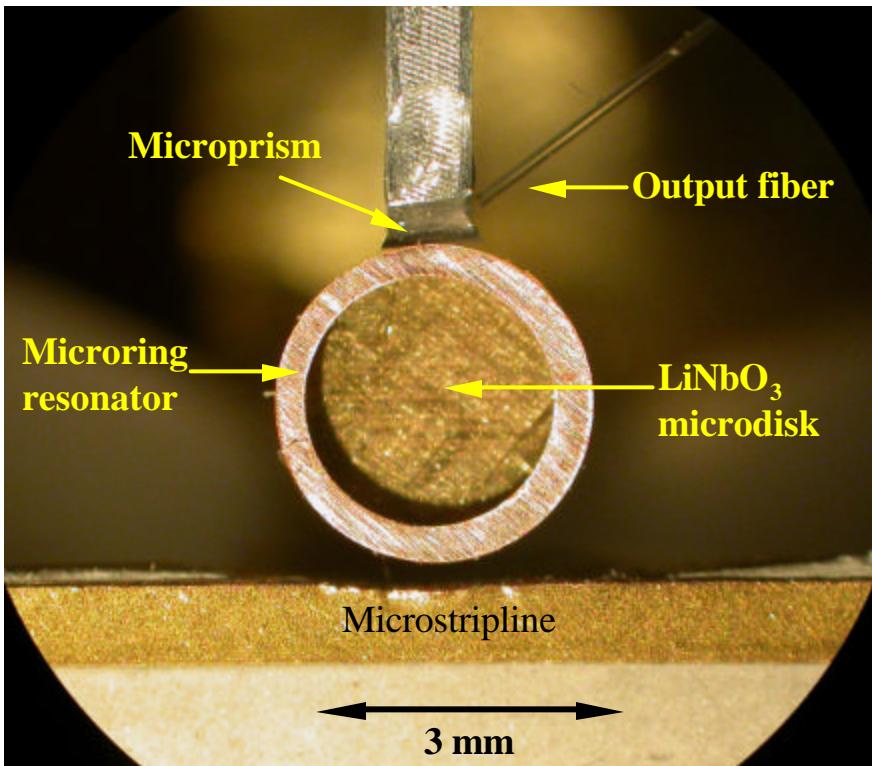
- 14.6 GHz LiNbO<sub>3</sub> microdisk modulator
  - ◆ 3 mm diameter LiNbO<sub>3</sub> microdisk
    - ◇  $D = 3 \text{ mm}$ ,  $t = 400 \text{ nm}$
    - ◇  $Q = 4 - 8 \times 10^6$ ,  $FSR = 14.6 \text{ GHz}$
  - ◆ Single prism optical coupling
  - ◆ Improved RF coupling
    - ◇ fine tuning of the ring/microstripline coupling coefficient: Critical coupling with 300 mm gap.
  - ◆ Modified E-field distribution
    - ◇ cylindrical symmetric E-field distribution
    - ◇ enhanced E-field intensity



# Power sensitivity of single-frequency linear modulation at 14.6 GHz

## Linear modulation sensitivity

- Dynamic range : > 70 dB
- SNR of 10 dB at -70 dBm (100 pW)
  - SNR = 1 at – 85 dBm RF input power
- Modulation bandwidth: 80 MHz
- 0 dBm RF saturation power

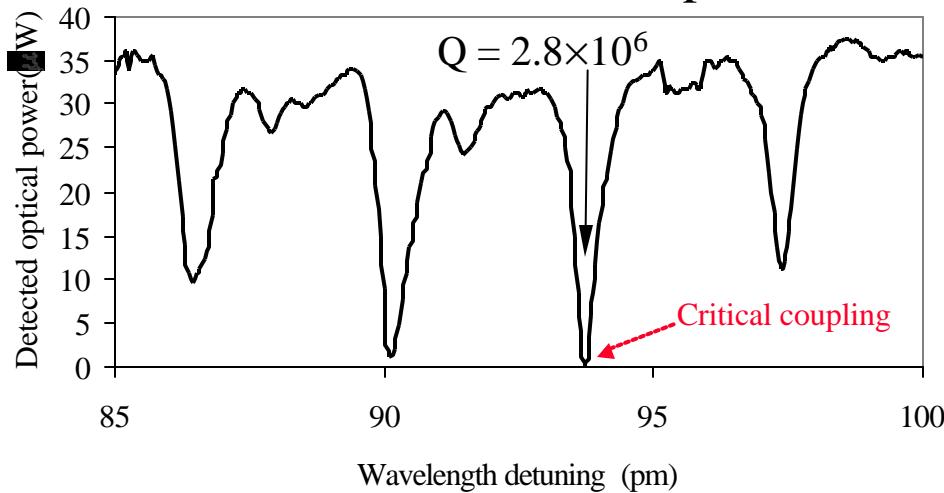


# Critical optical coupling and second-order nonlinear modulation with microdisk modulator

## ■ Transmission dips

- ◆ Zero DC optical power (at  $l_{\text{laser}} = l_{\text{res}}$ ) with critical coupling
  - ❖ reduction of optical noise generated by DC optical power
- ◆ Large second-order nonlinearity

Measured transmitted power



## Simulation

Optical input power =  $50 \mu\text{W}$   
Optical coupling factor ( $\kappa$ ) = 0.114  
Distributed loss (/cm) = 0.0075 ( $Q = 1.2 \times 10^7$ )

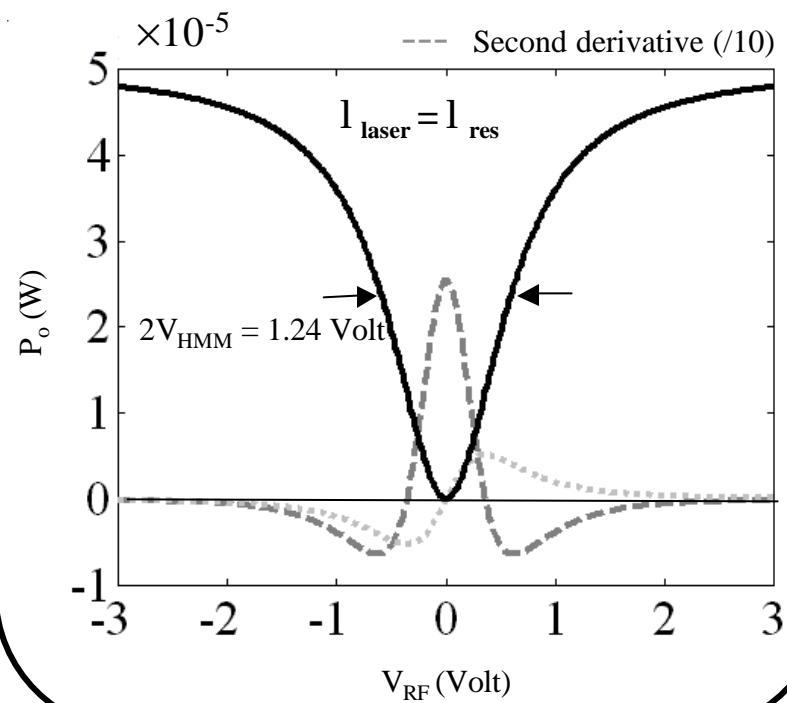
DC shift = 0.135 pm/V

Voltage gain factor (Volt) = 6

$Q = 3 \times 10^6$

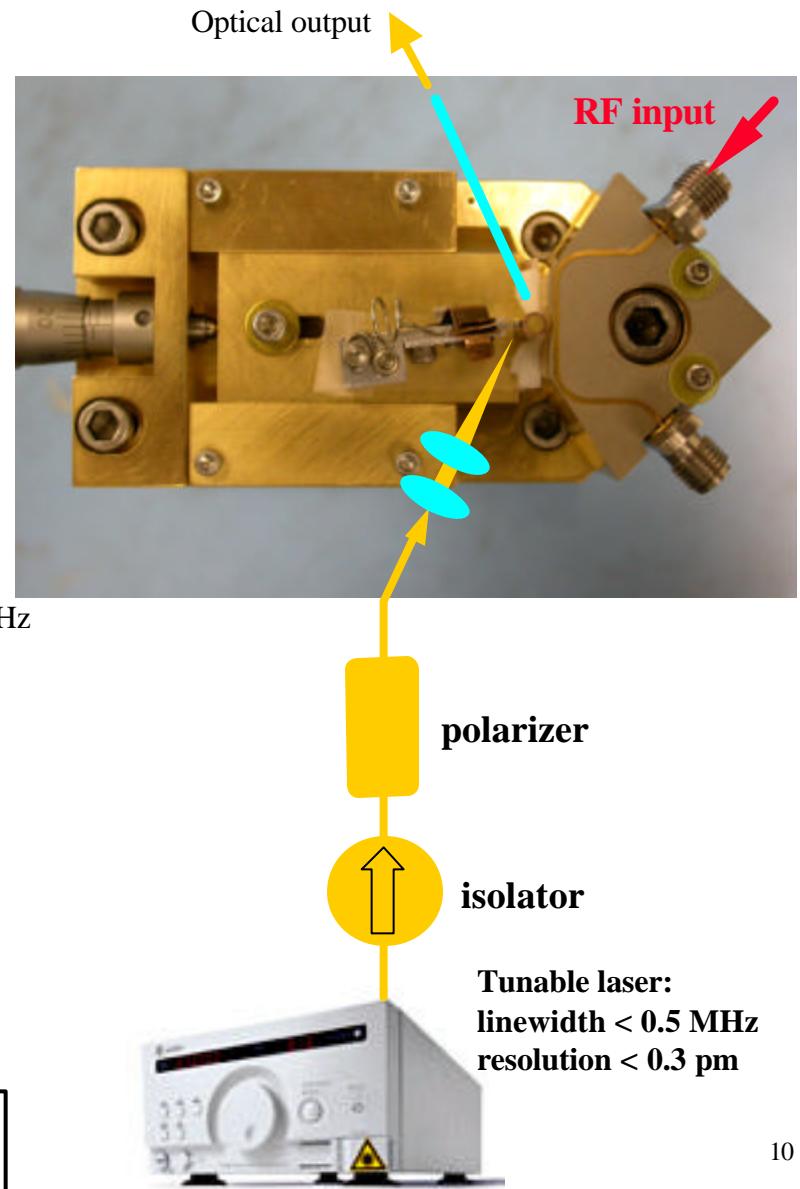
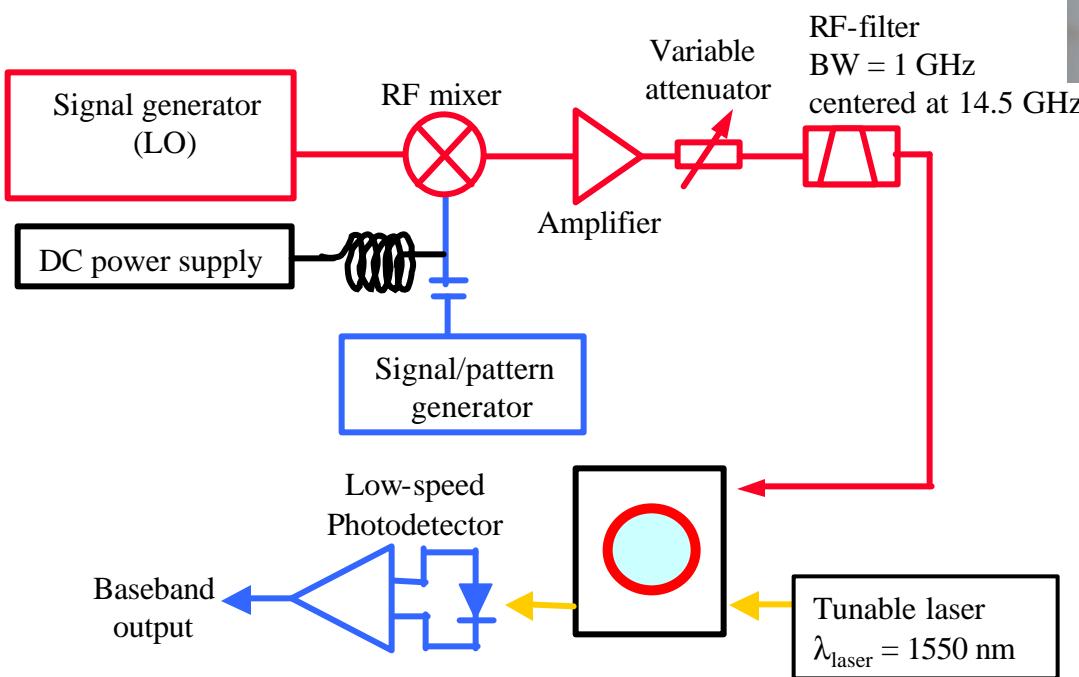
... First derivative (/10)

--- Second derivative (/10)



# Experimental arrangement

- Direct down-conversion RF-photonics link
  - ◆ Transmitted carrier RF format
    - ◊ DC biased mixer (IF port) to control modulation index ( $m$ )



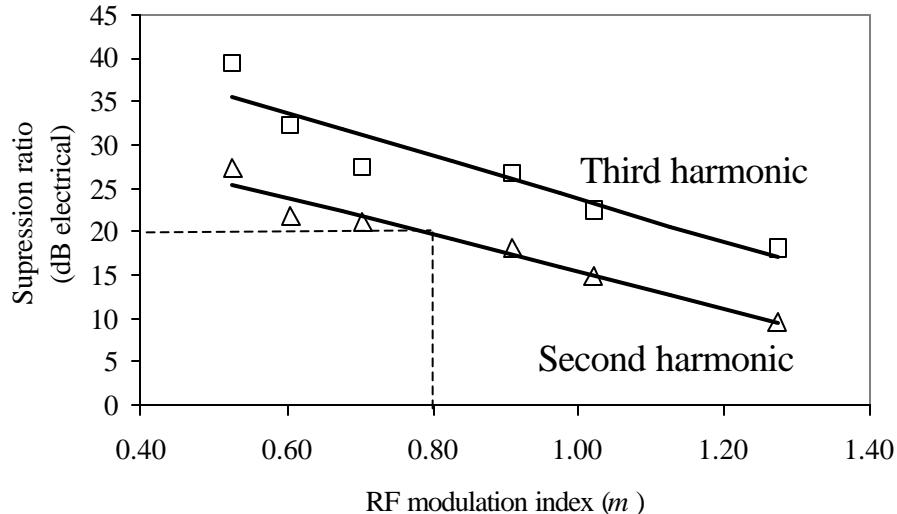
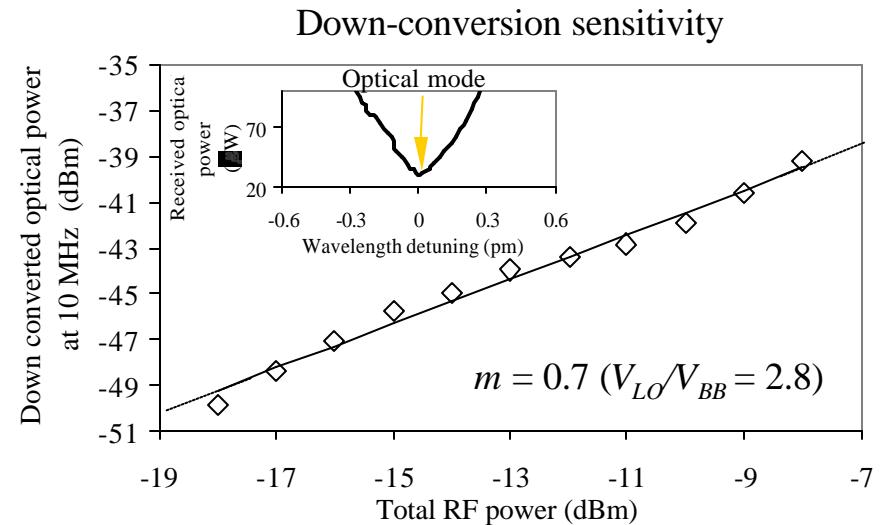
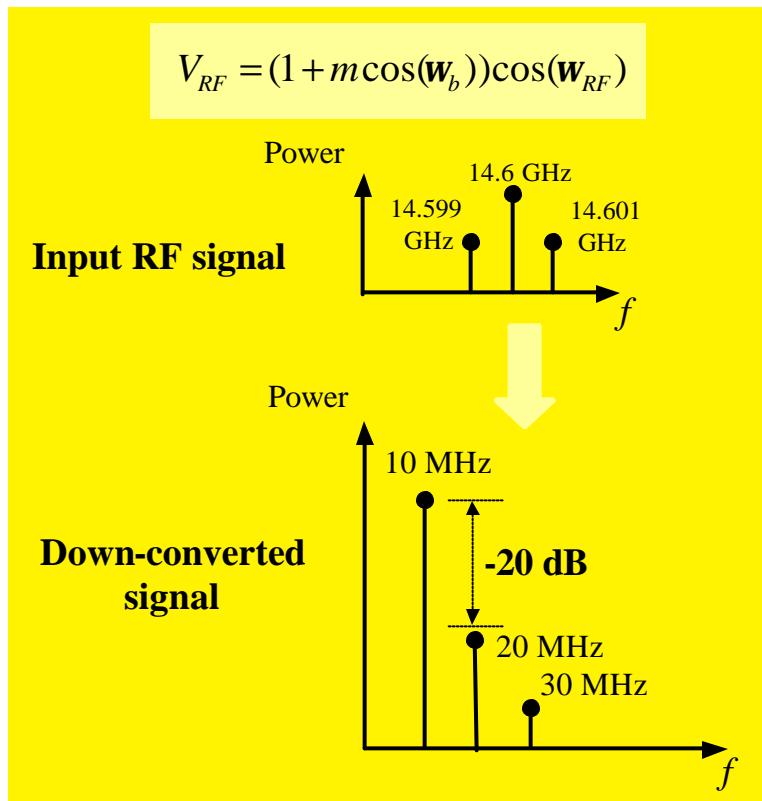
# Single tone down-conversion

## RF input signal

- Carrier frequency = 14.6 GHz
- Baseband frequency = 10 MHz
- Transmitted carrier format

## Photodetector

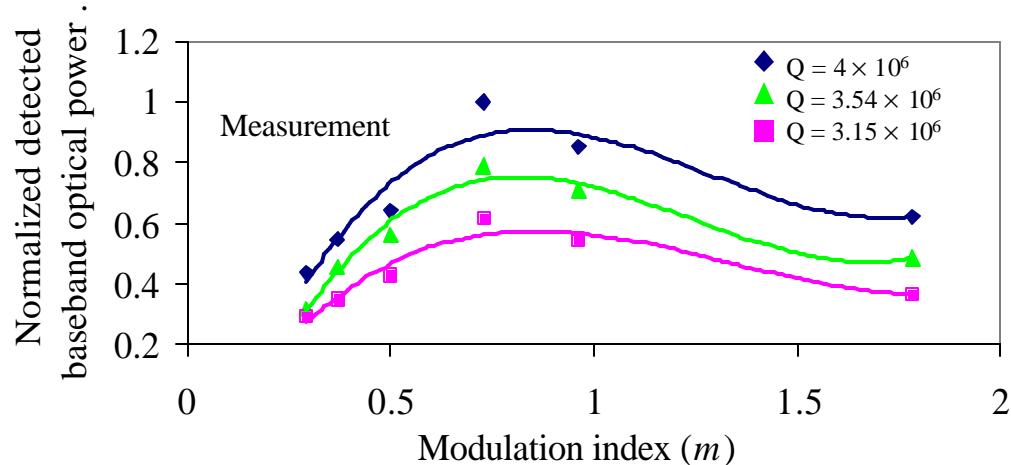
- Responsivity: 3 mV/mW
- Bandwidth: 100 MHz



# Optimizing modulation index for single frequency down-conversion efficiency

## ■ RF modulation format effect

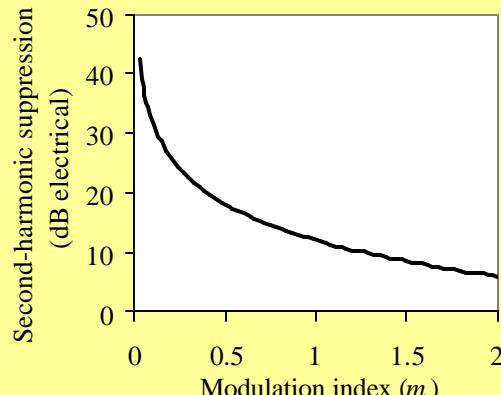
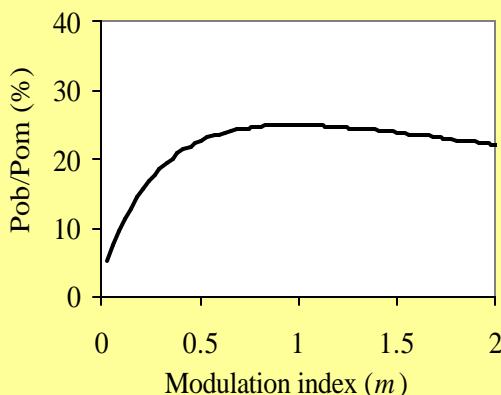
- ◆ Total received RF power » -15 dB
- ◆ Transmitted carrier format
  - ◇ modulation index  $m < 2$
- ◆ Optimized modulation index
  - ◇ measurement  $m \approx 0.7$
  - ◇ calculation (square law response)  $m \approx 0.7$



Calculated down-conversion efficiency and second-harmonic suppression ratio based on ideal square law response

(Down-conversion efficiency,  $P_{ob}/P_{om}$ , is defined as the ratio of modulated optical power at baseband frequency and the total modulated optical power)

At small signal regime ( $P_{RF} < -10\text{dBm}$ ) a modulation index of  $m = 0.7$  results in 25% down-conversion efficiency and about 15 dB second-harmonic suppression ratio.

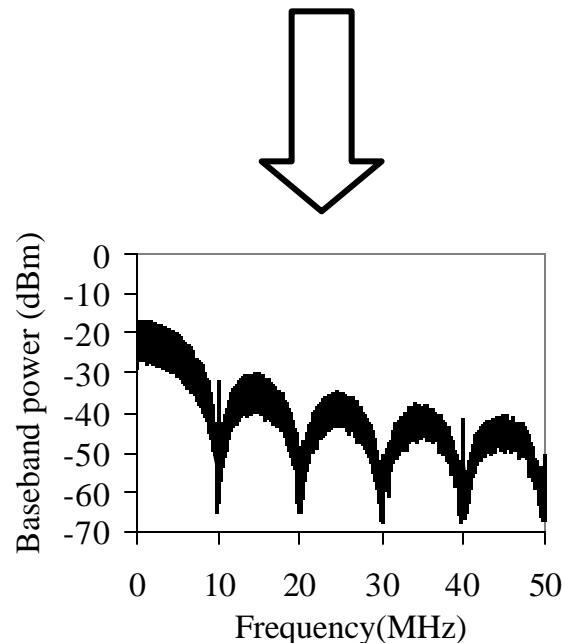
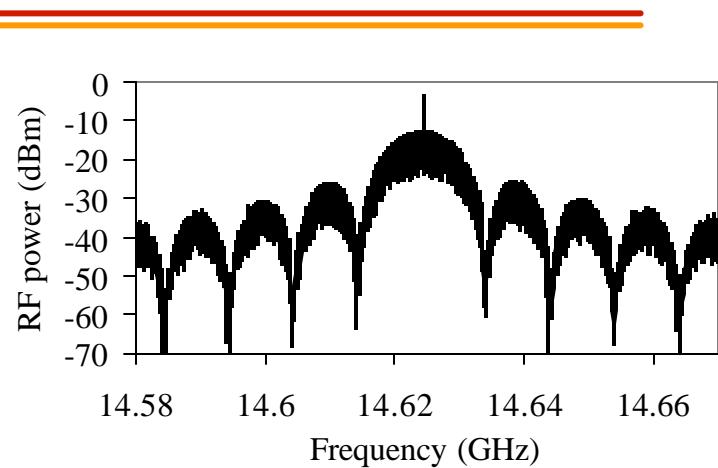
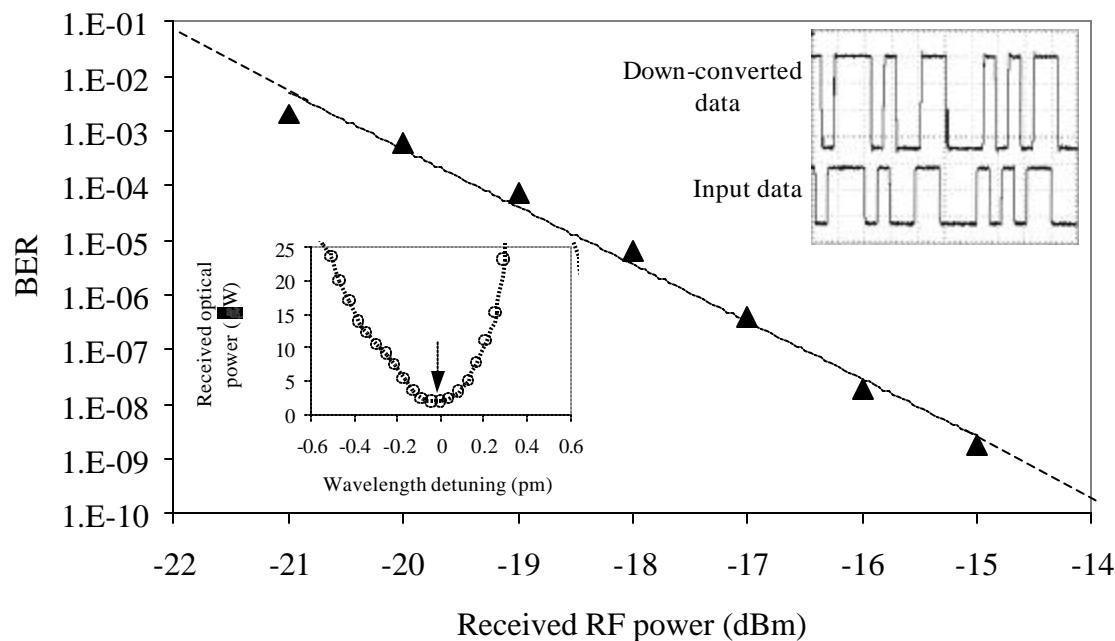


**Conclusion**

- $0.7 < m < 0.8$  simultaneously optimizes linearity and efficiency of the conversion

# Measured 10 Mb/s data down-conversion from 14.6 GHz carrier

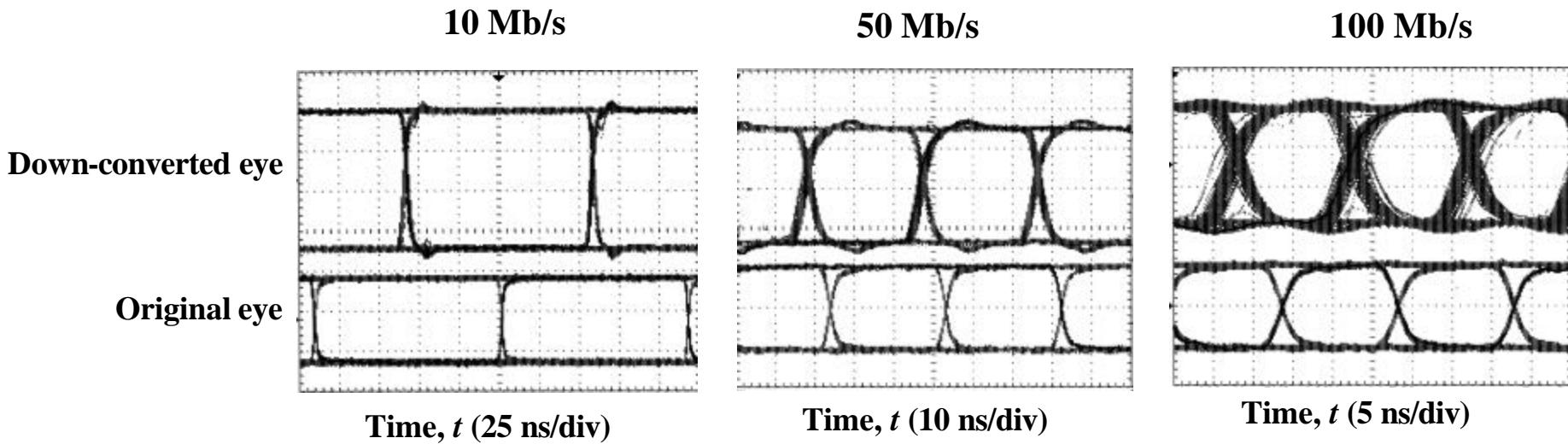
- **Ku-band photonic RF receiver**
  - ◆ Carrier frequency : **14.6 GHz**
  - ◆ Baseband: **10 Mb/s NRZ 2<sup>7</sup>-1 PBRS**
  - ◆ Received RF power measured within **100 MHz bandwidth centered at 14.6 GHz.**
  - ◆ Digital photo receiver
    - ◆ sensitivity: **-34.5 dBm**
    - ◆ bandwidth: **100 MHz**



# 10 Mb/s, 50 Mb/s and 100 Mb/s data down-conversion from 14.6 GHz carrier

## ■ Ku-band photonic RF receiver

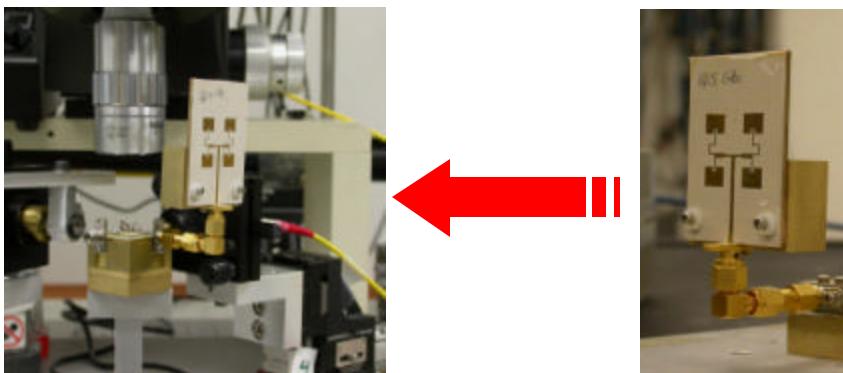
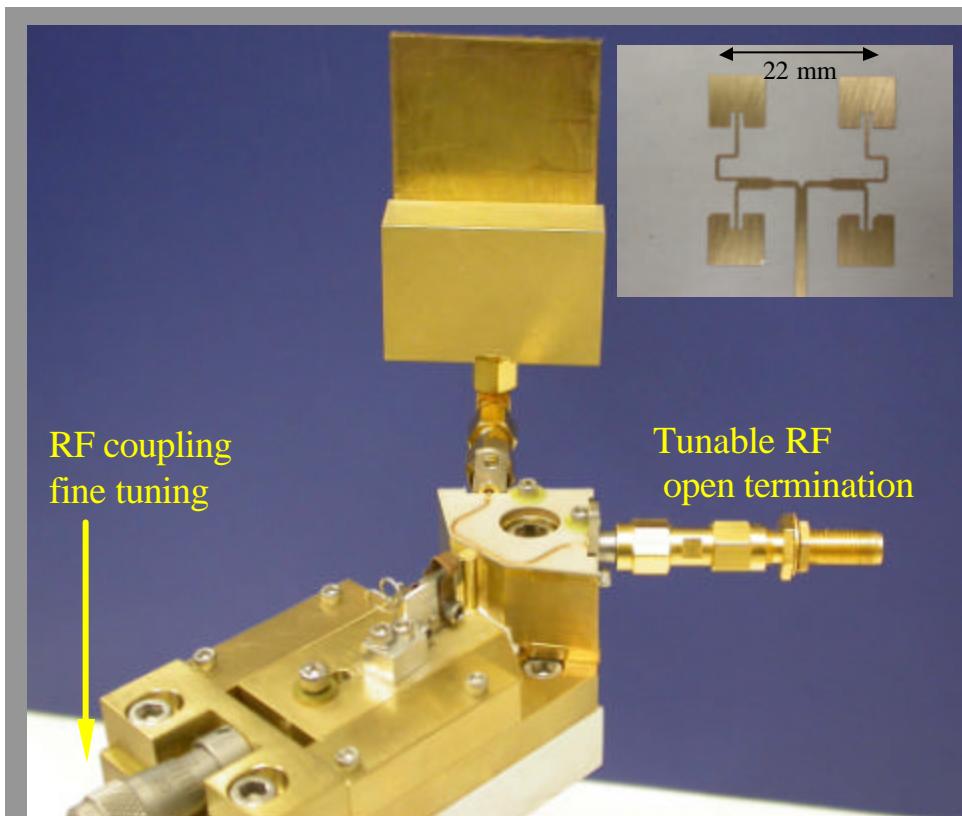
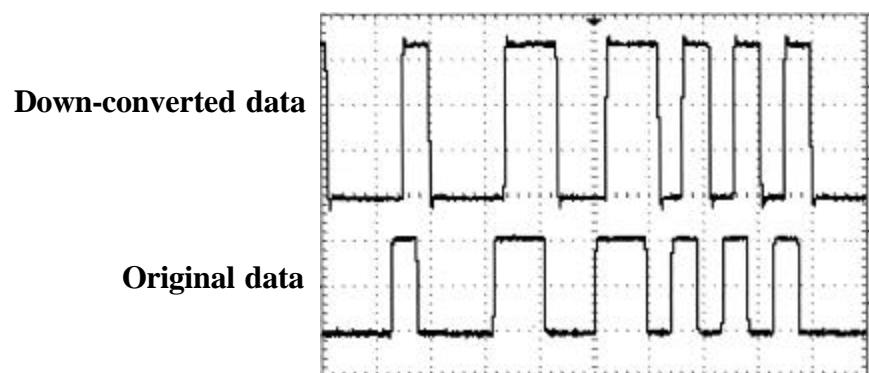
- RF carrier frequency : 14.6 GHz
- Baseband: 10 Mb/s, 50 Mb/s, 100 Mb/s NRZ PBRS  $2^7\text{-}1$
- $m = 0.7$
- Received RF power : -15 dBm (integrated power measured within 100 MHz bandwidth centered at 14.6 GHz)



# Wireless data communication with self-homodyne microdisk optical receiver

## Wireless self-homodyne microdisk RF-photonic receiver

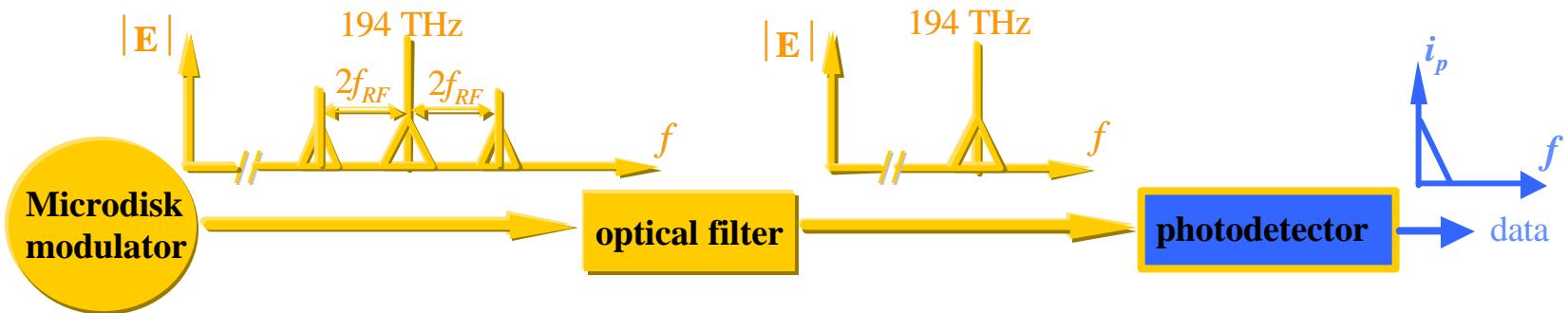
- 14.6 GHz 4-patch antenna array
- High sensitivity microdisk optical modulator
- RF-photonic nonlinear modulation
- Carrier frequency : 14.6 GHz
- Modulation index:  $m = 0.8$
- Baseband: 10 Mb/s NRZ PBRS 2<sup>7</sup>-1
- Input RF power to transmit antenna: 28 dBm



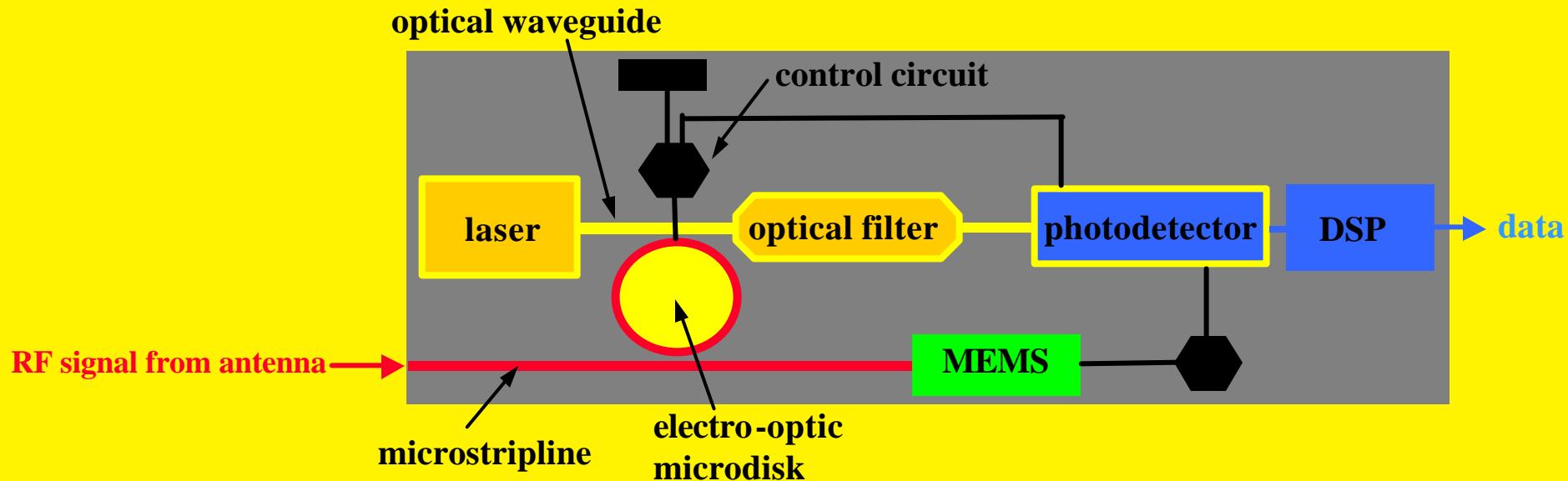
# Future: Photonic RF receiver

## ■ Optical filtering

- ♦ Reduce noise by eliminating the photocurrent from high-frequency components in the signal that are not used.



## ■ Monolithic integration of photonic RF receiver



# ELECTROMAGNETIC WORLD!

in which DC-to-light is used for communication

